

PJX8603

Complementary Enhancement Mode MOSFET – ESD Protected

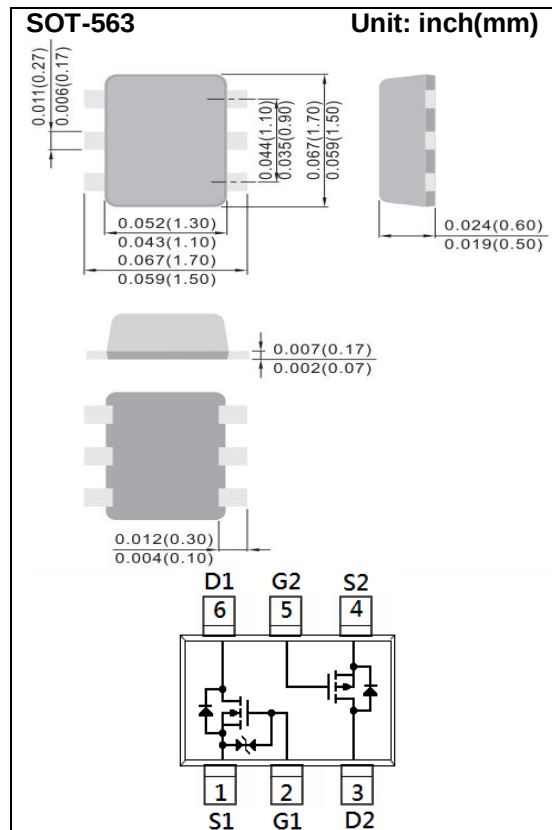
Voltage 50 / -60V **Current** 0.36A / -0.2A

Features

- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected 2KV HBM
- Lead free in compliance with EU RoHS 2011/65/EU directive
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case: SOT-563 Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.00009 ounces, 0.0026 grams
- Marking: X63



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	N-Ch LIMIT	P-Ch LIMIT	UNITS
Drain-Source Voltage		V _{DS}	50	-60	V
Gate-Source Voltage		V _{GS}	±20	±20	V
Continuous Drain Current		I _D	360	-200	mA
Pulsed Drain Current (Note 4)		I _{DM}	1200	-900	mA
Power Dissipation	T _a =25°C	P _D	300		mW
	Derate above 25°C		2.4		mW/°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150		°C
Typical Thermal resistance		R _{θJA}	417		°C/W
- Junction to Ambient (Note 3)					

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N-Channel Electrical Characteristics ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D = 250uA	50	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D = 250uA	0.5	0.9	1.0	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} = 10V, I _D = 500mA	-	1.26	1.5	Ω
		V _{GS} = 4.5V, I _D = 200mA	-	1.34	2.5	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 50V, V _{GS} =0V	-	-	1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±10	uA
Dynamic (Note 5)						
Total Gate Charge	Q _g	V _{DS} =25V, I _D =500mA, V _{GS} =4.5V	-	0.95	-	nC
Gate-Source Charge	Q _{gs}		-	0.34	-	
Gate-Drain Charge	Q _{gd}		-	0.32	-	
Input Capacitance	C _{iss}	V _{DS} =25V, V _{GS} =0V, f=1.0MHZ	-	36	-	pF
Output Capacitance	C _{oss}		-	11	-	
Reverse Transfer Capacitance	C _{rss}		-	6.6	-	
Turn-On Delay Time	td _(on)	V _{DD} =25V, I _D =500mA, V _{GS} =10V, R _G =6Ω (Note 1,2)	-	2.3	-	ns
Turn-On Rise Time	tr		-	20	-	
Turn-Off Delay Time	td _(off)		-	7	-	
Turn-Off Fall Time	tf		-	20	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _S	---	-	-	360	mA
Diode Forward Voltage	V _{SD}	I _S = 500mA, V _{GS} =0V	-	0.9	1.5	V

NOTES :

1. Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$
2. Essentially independent of operating temperature typical characteristics.
3. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
4. The maximum current rating is package limited.
5. Guaranteed by design, not subject to production testing.



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PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-60	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-1.0	-1.5	-2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V, I _D =-500mA	-	2.6	6	Ω
		V _{GS} =-4.5V, I _D =-200mA	-	2.9	7	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-48V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =+20V, V _{DS} =0V	-	-	+100	nA
Dynamic ^(Note 5)						
Total Gate Charge	Q _g	V _{DS} =-25V, I _D =-100mA, V _{GS} =-4.5V	-	1.1	-	nC
Gate-Source Charge	Q _{gs}		-	0.3	-	
Gate-Drain Charge	Q _{gd}		-	0.2	-	
Input Capacitance	C _{iss}	V _{DS} =-25V, V _{GS} =0V, f=1.0MHZ	-	51	-	pF
Output Capacitance	C _{oss}		-	15	-	
Reverse Transfer Capacitance	C _{rss}		-	2.2	-	
Turn-On Delay Time	td _(on)	V _{DD} =-25V, I _D =-100mA, V _{GS} =-10V, R _G =6Ω ^(Note 1,2)	-	4.8	-	ns
Turn-On Rise Time	tr		-	19	-	
Turn-Off Delay Time	td _(off)		-	52	-	
Turn-Off Fall Time	tf		-	32	-	
Drain-Source Diode						
Maximum Continuous Drain-Source Diode Forward Current	I _s	---	-	-	-200	mA
Diode Forward Voltage	V _{SD}	I _S =-500mA, V _{GS} =0V	-	-0.9	-1.5	V

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N-Channel TYPICAL CHARACTERISTIC CURVES

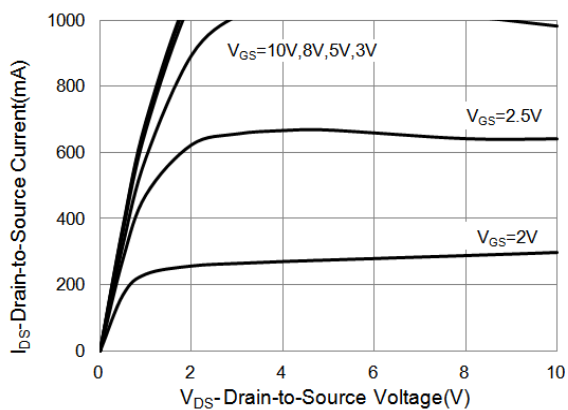


Fig.1 On-Region Characteristics

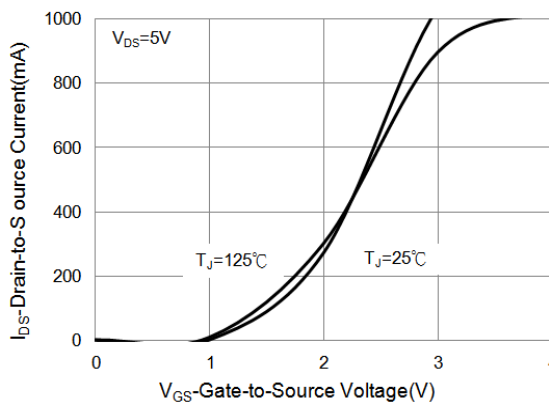


Fig.2 Transfer Characteristics

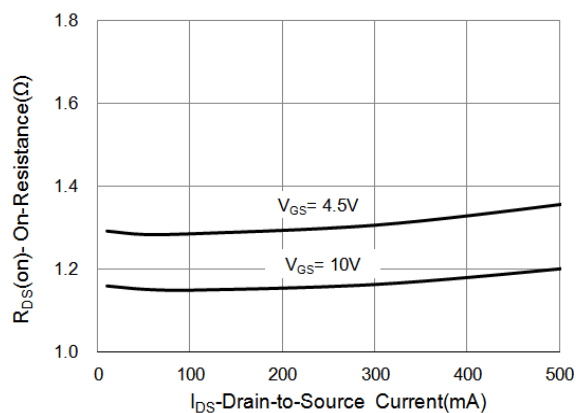


Fig.3 On-Resistance vs. Drain Current

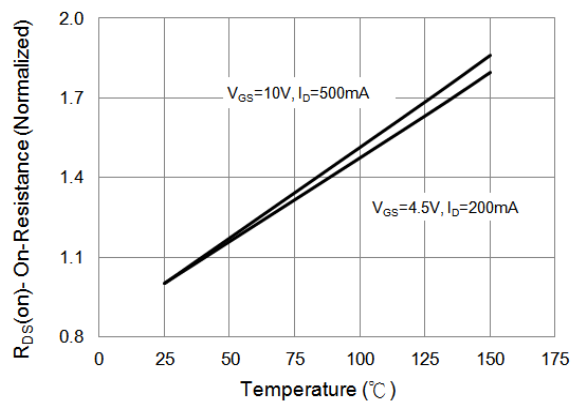


Fig.4 On-Resistance vs. Junction temperature

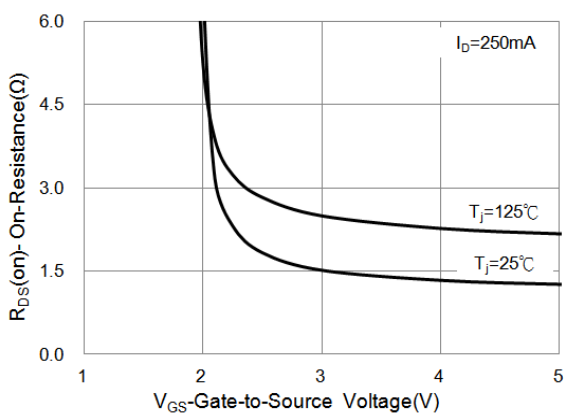


Fig.5 On-Resistance Variation with VGS.

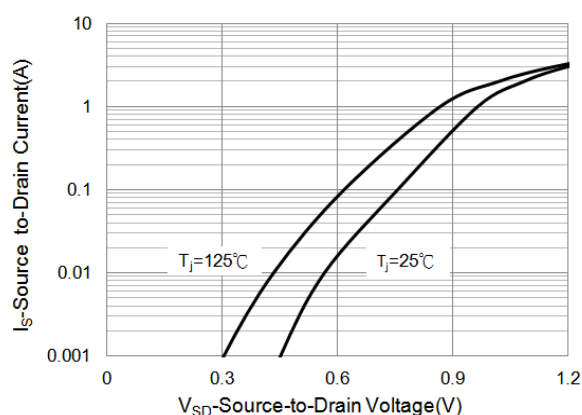


Fig.6 Body Diode Characteristics

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N-Channel TYPICAL CHARACTERISTIC CURVES

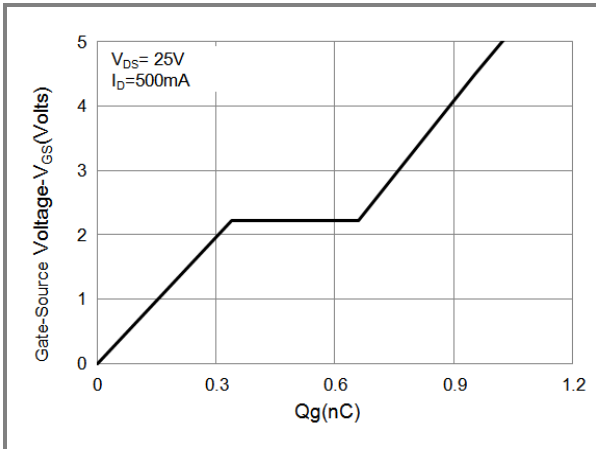


Fig.7 Gate-Charge Characteristics

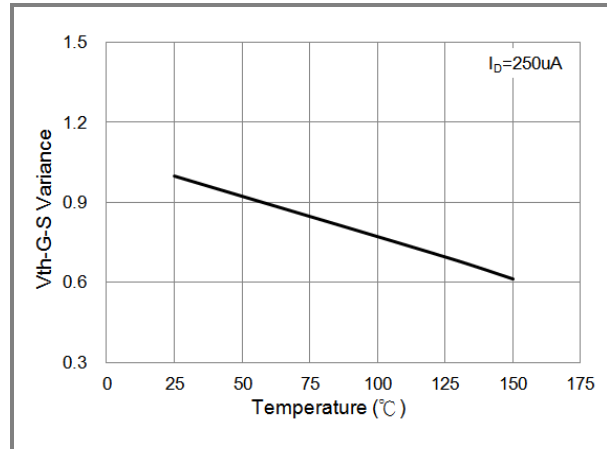


Fig.8 Threshold Voltage Variation with Temperature.

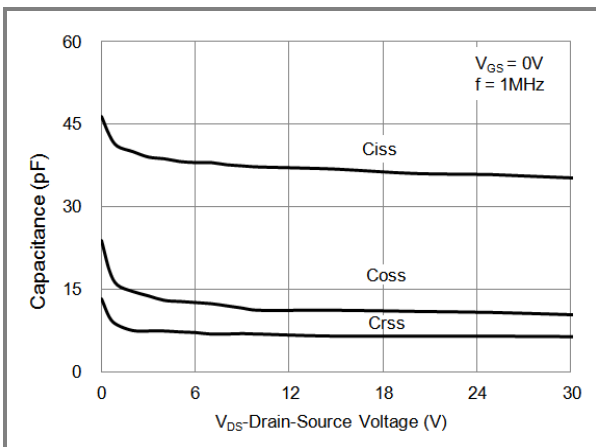


Fig.9 Capacitance vs. Drain-Source Voltage.

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P-Channel TYPICAL CHARACTERISTIC CURVES

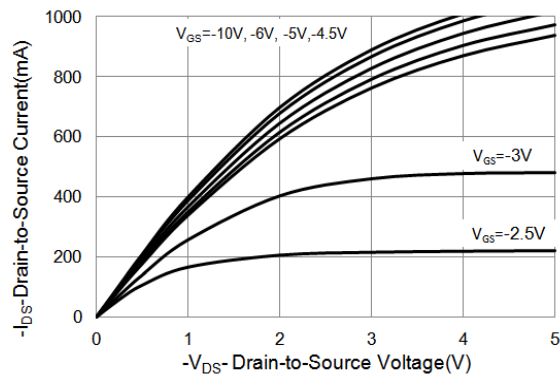


Fig.1 On-Region Characteristics

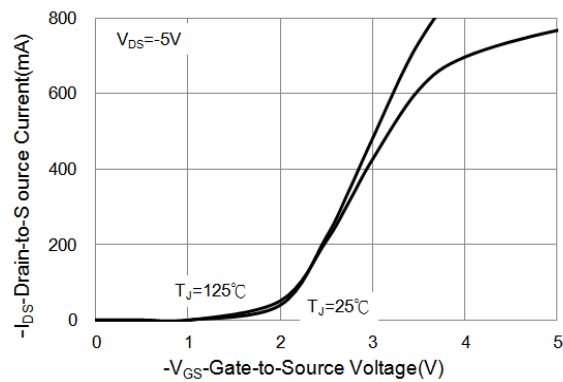


Fig.2 Transfer Characteristics

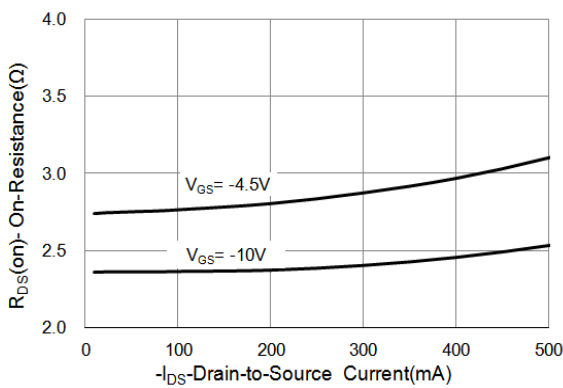


Fig.3 On-Resistance vs. Drain Current

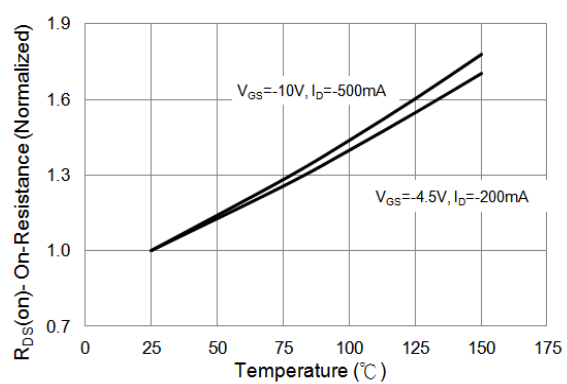


Fig.4 On-Resistance vs. Junction temperature

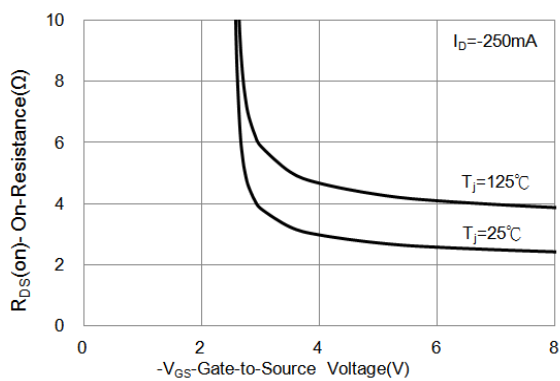


Fig.5 On-Resistance Variation with V_GS.

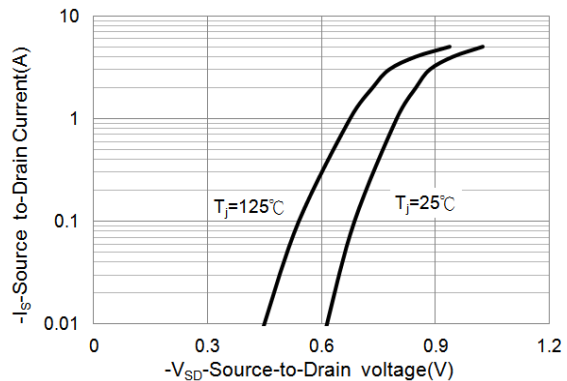


Fig.6 Body Diode Characteristics

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P-Channel TYPICAL CHARACTERISTIC CURVES

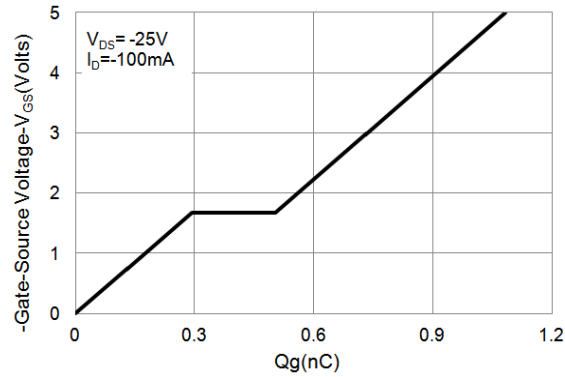


Fig.7 Gate-Charge Characteristics

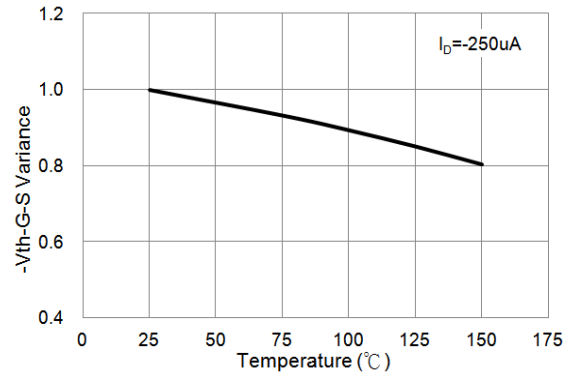


Fig.8 Threshold Voltage Variation with Temperature.

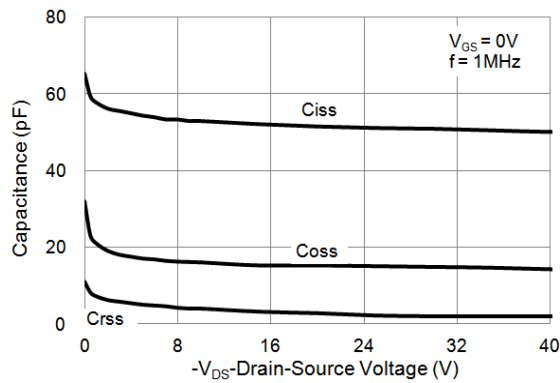


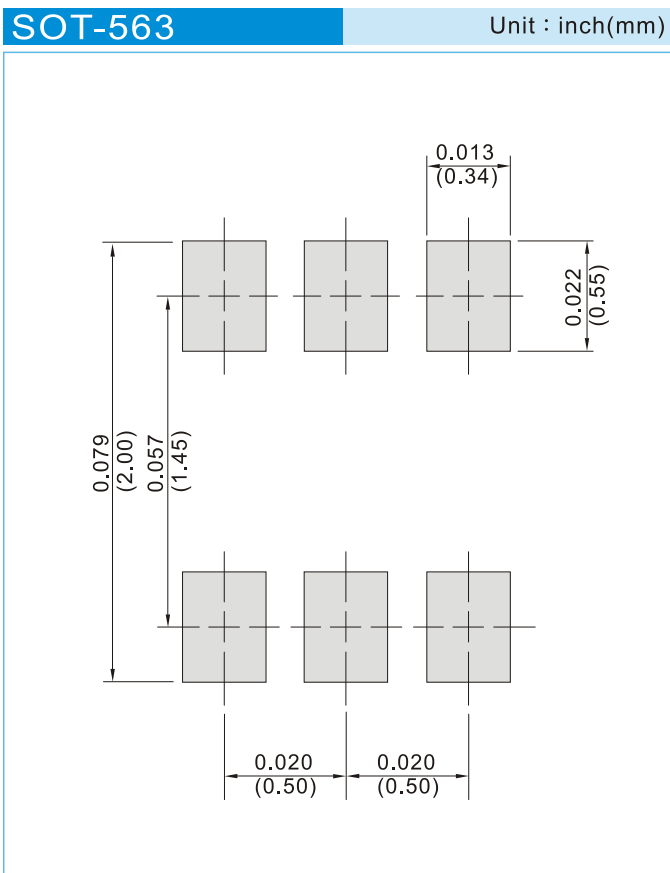
Fig.9 Threshold Voltage Variation with Temperature.

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PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJX8603_R1_00001	SOT-563	4K pcs / 7" reel	X63	Halogen free
PJX8603_R2_00001	SOT-563	10K pcs / 13" reel	X63	Halogen free
PJX8603_R1_00002	SOT-563	8K pcs / 7" reel	X63	Halogen free
PJX8603_R2_00002	SOT-563	20K pcs / 13" reel	X63	Halogen free

MOUNTING PAD LAYOUT





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